

• Approx. Weight : 0.0003 ounces, 0.0086 grams

Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20		
Gate-Source Voltage	V _{GS}	<u>+</u> 12	V		
Continuous Drain Current (Note 4)		ID	8	A	
Pulsed Drain Current (Note 1)		I _{DM}	32		
Power Dissipation	T _A =25°C	_	2	W	
	Derate above 25°C		16	mW/ °C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 4,5)		R _{0JA}	62.5	°C/W	



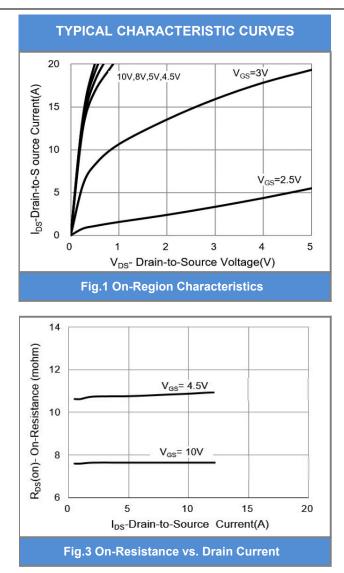
Electrical Characteristics (T_A=25[°]C unless otherwise noted)

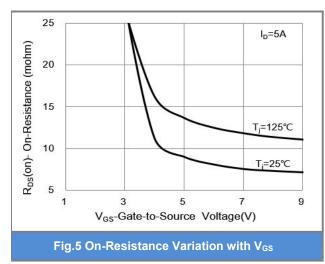
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =10A	-	7.5	11.5	mΩ
		V _{GS} =4.5V, I _D =6A	-	11	15	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)			·			
Total Gate Charge	Qg	V _{DS} =15V, I _D =10A, V _{GS} =4.5V ^(Note 2,3)	-	6.9	-	nC
Gate-Source Charge	Q_gs		-	2.7	-	
Gate-Drain Charge	Q_gd		-	1.8	-	
Input Capacitance	Ciss	V _{DS} =20V, V _{GS} =0V, f=1MHZ	-	781	-	pF
Output Capacitance	Coss		-	158	-	
Reverse Transfer Capacitance	Crss		-	92	-	
Turn-On Delay Time	td _(on)	V_{DS} =15V, I _D =10A, V_{GS} =10V, R _G =6Ω (Note 2,3)	-	5.4	-	
Turn-On Rise Time	tr		-	86	-	ns
Turn-Off Delay Time	td _(off)		-	20	-	
Turn-Off Fall Time	tf		-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is				1 5	•
Diode Forward Current			-	-	1.5	A
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.73	1	v

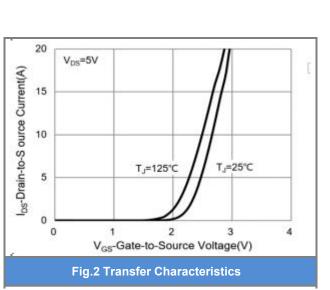
NOTES :

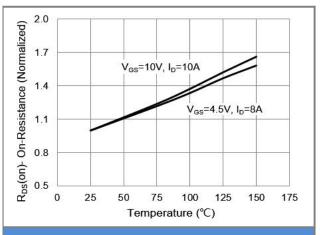
- 1. Pulse width300us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J=25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



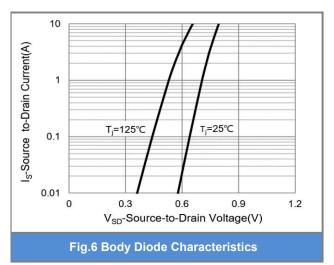




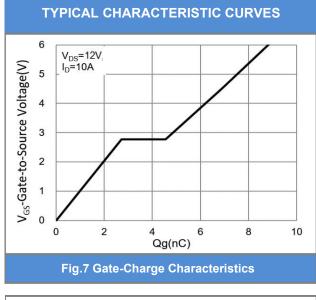












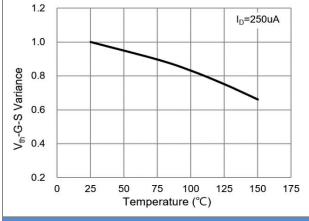
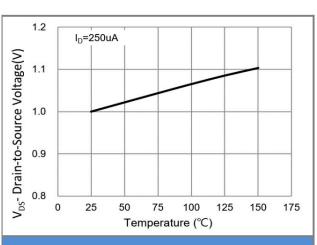
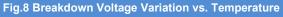


Fig.9 Threshold Voltage Variation with Temperature





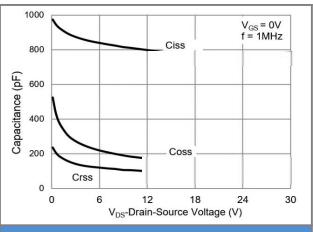


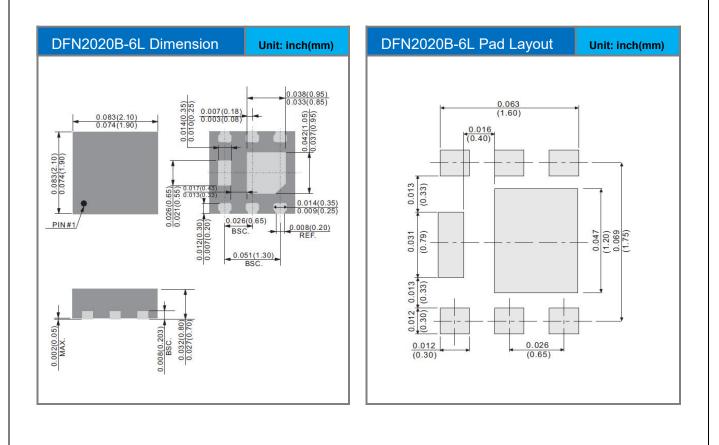
Fig.10 Capacitance vs. Drain-Source Voltage



Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type
CSM212N8D2-2	DFN2020B-6L	3K pcs / 7" reel

Packaging Information & Mounting Pad Layout





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